

SERVICE SHEET FOR



TRANSISTOR PORTABLE Q3



CIRCUIT ANALYSIS

Battery consumption 15 mA with no signal input.							
Code	Transistor Function	Type	Ref. No.	Ec	Ic	Eb	Ee
V1	Frequency Changer	Yellow Circle 1	865182	-2.4(-1.6)	0.5 mA	-0.6(-0.3)	-0.5(-0.45)
V2	1st I.F. Amplifier	Yellow Circle 2	865183	-5.7(-5.6)	1.2 mA	-0.66(-0.3)	-0.58(-0.5)
V3	2nd I.F. Amplifier	Yellow Circle 3	865184	-5.7(-5.6)	1.05 mA	-0.9(-0.8)	-0.73(-0.65)
V4	A.F. Amplifier	Yellow Circle 4	865185	-5.5(-5.3)	4.0 mA	-1.0(-0.6)	-0.85(-0.80)
V5	Output	Yellow Circle 5	865186	-8.95(-8.95)	2.0 mA	-0.2(-0.18)	—
V6	Output	Yellow Circle 5	865186	-8.95(-8.95)	2.0 mA	-0.2(-0.18)	—

NOTE:—All measurements taken on M.W. band with no signal input. Gang fully meshed. Measurements taken with an Avometer model 8 instrument which has a resistance of 20,000 ohms per volt. The figures in brackets are the readings obtained with an Avometer model 7.

TRIMMING PROCEDURE

Apply signal as below:-	Set receiver controls to:	Adjust in order for maximum output:
1. 470 kc/s between chassis and junction of S1 and CS.	Low frequency end of M.W.	Ferrite cores of T3, T2 and T1.
2. As 1 but 600 kc/s.	M.W. 500 metres.	Iron dust core of L5.
3. As 1 but 1500 kc/s.	M.W. 200 metres.	Trimmer C7.
4. Repeat 2 and 3 until calibration is correct.		
5. As 1 but 214 kc/s.	L.W. 1400 metres.	Trimmer C4.
6. 214 kc/s to rod aerial via loop at 50 cms from centre of rod with L1 nearest loop.	L.W. 1400 metres.	Adjust position of L4 on rod aerial and seal in position with Polystyrene Dope.
7. As 6 but 600 kc/s.	M.W. 500 metres.	Adjust position of L1 on rod aerial.
8. As 6 but 1500 kc/s.	M.W. 200 metres.	Trimmer C2.
9. Repeat 7 and 8 until tracking is correct. Seal L1 with Polystyrene Dope.		

NOTE:—The alignment of the aerial circuits, tests 6 to 9, must be carried out with the chassis and speaker mounted on the front panel.

Precautions

1. Do not make continuity measurements with the transistors in circuit.
2. Do not carry out soldering operations with the receiver connected to test equipment.
3. When replacing a transistor leave the leads at least $\frac{3}{8}$ " long and use as little heat as possible.

D.C. Tests

1. Check the battery voltage: if this shows less than 6.5 volts on load the battery should be discarded.
2. Check the emitter voltages of V1 to V4, these voltages should be within $\pm 25\%$ of the values shown on the circuit.
3. Measure the collector currents of V5 and V6. (Normally between 1 and 5 mA with no signal input).
NOTE:—If the readings obtained in 2 and 3 are normal, a transistor fault is unlikely.
4. If any of the readings obtained are abnormal, check collector and base voltages of the transistor in question: note that V2 and V3 derive their base bias from the emitter voltage of V4.

Notes:-

- (a) A high emitter voltage would indicate an open circuit emitter resistor or a faulty bias chain, or transistor. To check for a faulty transistor the simplest method is to remove the forward bias on the base; the emitter voltage should then be less than 0.1 volts.
To test V1, V4 or V5 and V6 disconnect R3, R11 or R15.
To test V2 short circuit the junction of R9 and R10 to chassis.
Note:—Due to the circuit arrangement it is not practicable to apply a similar test to V3, which is, in any case, unlikely to develop a fault of this nature.
- (b) A low emitter voltage would indicate incorrect bias or collector voltages, or a faulty transistor.

Signal Tests.

1. If the fault cannot be located by the tests outlined so far, it will be necessary to trace the signal through the circuit. Due to the large variations in test gear, there is little point in quoting figures of sensitivity. The best method is to check the sensitivity at various points in the circuit against a known good receiver. The signal should be injected into the audio circuits via an electrolytic capacitor and into the R.F. circuits via a 0.1 μ F paper capacitor.
2. Open circuit coupling or decoupling capacitors can be checked by temporarily connecting another capacitor of the appropriate value in parallel with the suspect component.
3. Distortion is most likely to be caused by the output stages. The best method of test is to inject an audio signal at 400 c/s to the base of V4, and using an oscilloscope observe the voltage waveform across R17. Due to the Class B operation the voltage across R17 will be composed of double frequency half sine waves, the amplitude of adjacent peaks, ideally, should be equal, but a discrepancy of up to 30% is permissible before audible distortion becomes objectionable. If the degree of unbalance is greater than 30% one of the output transistors should be replaced with a transistor that gives a better balance.

Note:—Fixed neutralising is used and the values do not need to be changed when replacing an I.F. stage.

The aerial circuit comprises a ferrite rod with separate coils for Long and Medium Waves. L1 and L2 in series form the M.W. coil, tuned by C2 and C3, whilst C4 and C6 are switched across the L.W. coil, L4, to ensure that this coil is effectively short-circuited on M.W. The L.W. coil is tuned by C2 and C3 with C1 in parallel to restrict the coverage. Taps on the aerial coils provide the correct impedance to match into the base of the self-oscillating mixer V1.

The oscillator coil, L5, is tuned on M.W., by C7, C8 and C9, and on L.W. by C4 and C6 in parallel with this combination.

V1 oscillates due to feedback between emitter and collector via L5. Initially the base of V1 is biased negatively with respect to the emitter by the potentiometer R3 and R4. The amplitude of oscillation builds up until, over part of the cycle, the emitter is driven negative with respect to the base and the stage is cut-off. Thus rectification of the oscillator voltage occurs at the emitter and C10 charges in a direction to oppose the original bias, stabilising the amplitude of oscillation. R2 prevents spurious oscillation at the high frequency end of M.W.

Mixing of the signal and local oscillator frequencies occurs at the base emitter junction of V1. After amplification the required difference frequency is selected by T1, which also provides the correct matching between V1 collector and V2 base.

After further amplification by V2 and V3, the 1st and 2nd I.F. amplifiers, the I.F. signal is fed to the diode detector, D1, the required audio voltage being developed across the volume control, R10, which also serves as the diode load. Neutralisation of the I.F. amplifiers is provided by C14 and C18.

The 'earthy' end of R10 is connected to the emitter of V4, the audio driver stage, and is therefore at about 1 volt negative with respect to chassis: this voltage is used to provide the forward base bias for V2, via the A.G.C. feed resistor R8. When the receiver is tuned to a station the rectified carrier voltage, developed across R10, causes the diode end of R10 to become positive with respect to the emitter connection, thus reducing the bias of V2 and controlling the gain. The base bias of V3 is also derived from the emitter of V4.

After amplification by V4 the audio signal is fed to the output stages, V5 and V6, via the push-pull driver transformer T4. Bias for V4 is obtained from the potential divider R11 and R12. C24 acts as an additional I.F. filter whilst C25 restricts the ringing which occurs in the driver transformer.

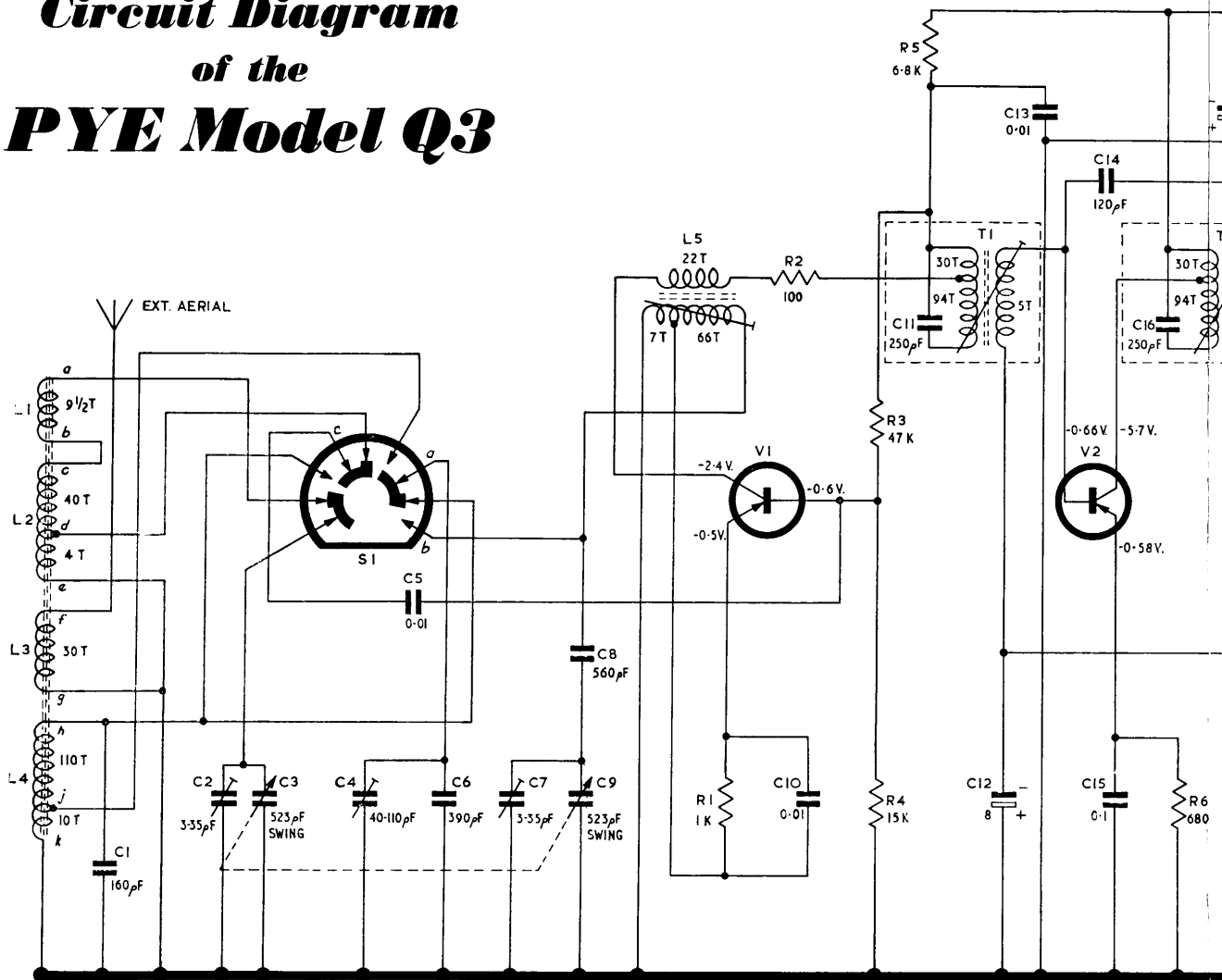
The output stages operate in Class B, being driven in the conducting direction by the negative half-cycles of signal. The potential divider formed by R15 and R16 provides forward bias, thus establishing the quiescent collector current of each stage at about 1—5 mA. At full output the peak current of each stage rises to 125 mA, whilst the average battery current at normal listening levels would be 25—35 mA. C26 removes most of the objectionable distortion which arises from the Class B operation of the output stages.

Stabilisation of the DC operating conditions of all stages is achieved by the use of emitter resistors.

Replacement Output Transistors

If one of the output transistors becomes faulty it will be advisable to replace both transistors in order to ensure correct matching: replacement output transistors should be ordered under Part Number 865186.

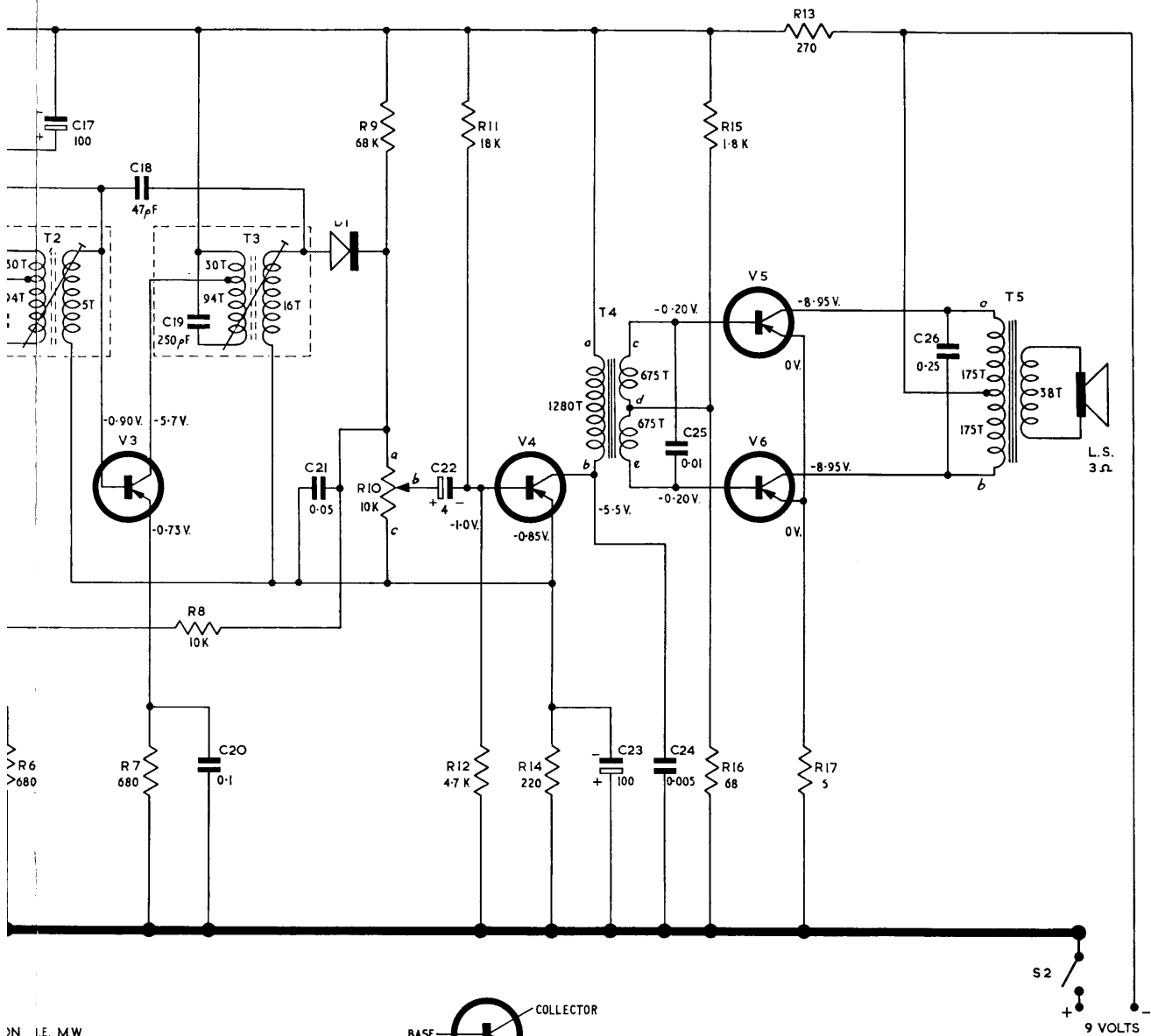
Circuit Diagram of the PYE Model Q3



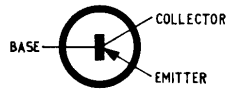
WAVECHANGE SWITCH SHOWN IN ANTI-CLOCKWISE POSITION I.E.
ALL RESISTORS IN OHMS UNLESS OTHERWISE STATED.
ALL CAPACITORS IN μF UNLESS OTHERWISE STATED

CAPACITORS					CAPACITORS (cont.)					RESISTORS									
Specification	\pm	Volts	Fig.	No.	Specification	\pm	Volts	Fig.	No.	Ohms									
C1	160 μF Polystyrene	...	2%	125	2	653246	C24	0.005 μF Tubular	...	150	1 & 2	669103	R1	1 K			
C2*	3.35 μF Trimmer	...			2	800404	C25	0.01 μF Tubular	...	150	2	669104	R2	100			
C3	523 μF Gang	...			1 & 2	800386	C26	0.25 μF Tubular	...	150	1 & 2	668723	R3	47 K			
C4	40-110 μF Trimmer	...			2	653239	*Part of Gang Capacitor		†Integral Part of I.F. Transformer				R4	15 K			
C5	0.01 μF Tubular	...			150	1 & 2	669104	TRANSFORMERS					R5	6.8 K			
C6	390 μF Polystyrene	...			2%	125	2	653249	Specification		Fig.	No.	R6	680			
C7*	3.35 μF Trimmer	...			1 & 2	667949	1st I.F. Trans.		{ Prim. 3.5 Ω	1 & 2	077081	R7	680		
C8	560 μF Polystyrene	...			2%	125	2	668720	2nd I.F. Trans.		{ Sec. 0.25 Ω	1 & 2	077081	R8	10 K
C9	523 μF Gang	...			1 & 2	667950	3rd I.F. Trans.		{ Prim. 3.5 Ω	1 & 2	077082	R9	68 K		
C10	0.01 μF Tubular	...			150	2	668720	Driver Trans.		{ Sec. 0.5 Ω	1	771799	R10*	10 K Vol. Control, 10 switch	
C11†	250 μF Polystyrene	...			2%	125	2	668717	Output Trans.		{ Prim. 137 Ω	1	077205	R10*	10 K Vol. Control, w double pole switch
C12	8 μF Electrolytic	...			6	1 & 2	667948	1st I.F. Trans.		{ Sec. 0.26 Ω	1 & 2	077081	R11	18 K	
C13	0.01 μF Tubular	...			150	2	667950	2nd I.F. Trans.		{ Prim. 3.5 Ω	1 & 2	077081	R12	4.7 K	
C14	120 μF Polystyrene	...			5%	125	1	653232	3rd I.F. Trans.		{ Sec. 0.25 Ω	1 & 2	077081	R13	270
C15	0.1 μF Tubular	...			5%	125	1	653323	Driver Trans.		{ Prim. 3.5 Ω	1 & 2	077082	R14	220
C16†	250 μF Polystyrene	...			2%	125	2	653219	Output Trans.		{ Sec. 0.5 Ω	1	771799	R15	1.8 K
C17	100 μF Electrolytic	...			6	1 & 2	667950	1st I.F. Trans.		{ Prim. 137 Ω	1	771799	R16	68	
C18	47 μF Polystyrene	...			5%	125	1	653323	2nd I.F. Trans.		{ Sec. 0.5 Ω	1	771799	R17	5
C19†	250 μF Polystyrene	...			2%	125	2	653219	3rd I.F. Trans.		{ Prim. 3.5 Ω	1 & 2	077082				
C20	0.1 μF Tubular	...			150	2	668720	Driver Trans.		{ Sec. 0.26 Ω	1	077205					
C21	0.05 μF Tubular	...			150	1 & 2	668717	Output Trans.		{ Prim. Start to Finish 4.2 Ω	1	077205					
C22	4 μF Electrolytic	...			6	1 & 2	667948	1st I.F. Trans.		{ Sec. 0.26 Ω	1 & 2	077081					
C23	100 μF Electrolytic	...			6	2	667950	2nd I.F. Trans.		{ Prim. 3.5 Ω	1 & 2	077081					

*Refer to Fig. 1



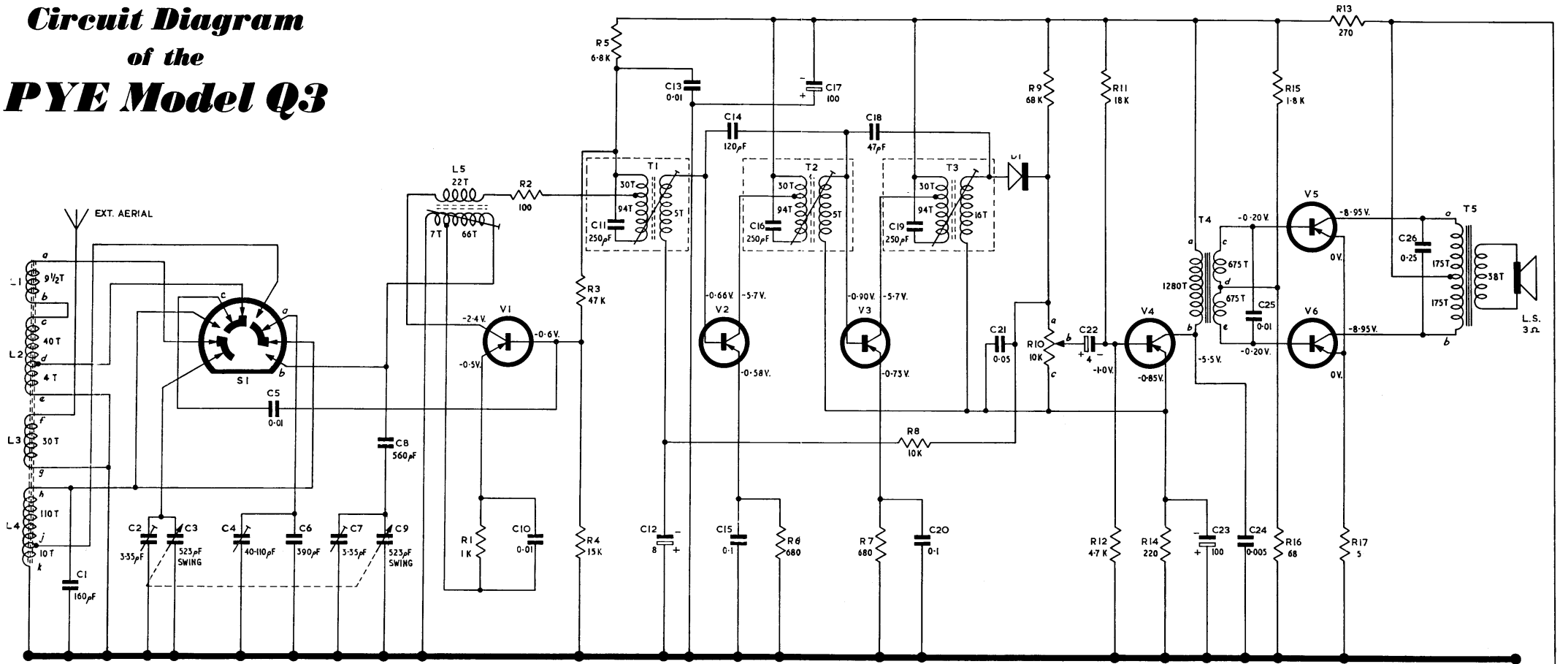
DN I.E. M.W.



KEY TO TRANSISTORS.

RESISTORS			INDUCTORS			MISCELLANEOUS		
±	Fig.	No.	Specification	Fig.	No.			No.
...	20%	2	L1 M.W. Adjusting Coil	1	073751	Cabinet	...	063238
...	10%	1 & 2	L2 Main Aerial Winding			Handle	...	071567
...	10%	2	L3 L.W. and External Aerial Coil			Motif; Pye	...	048302
...	10%	2	L4			Backing; Motif	...	071506
...	10%	2	L5 M.W. & L.W. Oscillator Coil			Escutcheon; Motif	...	071494
...	20%	2				Knob Assembly; Large: Tuning	...	073729
...	20%	2				Knob Assembly; Large: Volume*	...	073730
...	10%	1 & 2				Knob Assembly; Large: Volume-Off*	...	073749
...	10%	1 & 2				Knob Assembly; Small: Wavechange	...	073731
rol, less						Spring; Knob	...	709526
...		1						
rol, with wotch		2						
...	10%	1 & 2						
...	10%	2						
...	10%	1 & 2						
...	20%	2						
...	5%	2						
...	5%	2						
...	10%	2						
			SWITCHES, ETC.					
			Specification	Fig.	No.			
			S1 Wavechange Switch—2 position	...	1	083144		
			S2* On/Off Switch	...	1 & 2	830171		
			LS Loudspeaker 7" x 4"	...	1	850279		
			D1 OA 70 Diode	...	2	707301		
			*Refer to Fig. 1			*Refer to Fig. 1		

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